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## AMENDMENTS

(Japanese Law Section 11 based on PCT Article 34 (2)(b))

To : Examiner of the Patent Office, Misako ANZAI

## 1. Identification of the International Application

PCT/JP2005/002560

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## 4. Item to be amended

Claims

## 5. Subject matter of amendments

As per the attached paper, we amend the claims. The amendments are as follows.

The limitations that "the source gas includes at least one of nitrogen and ammonia, and the other materials include at least one Group III element selected from the group consisting of gallium, aluminum, and indium and a flux material" and that "the single crystal is a Group III nitride single crystal" have been added to claim 1.

Accordingly, claim 13 has been canceled.

With the cancellation of claim 13, claims 14 and 23-25 have been amended to depend from claim 1, and claim 15 has been amended to depend

from claim 2.

**6. List of attached documents**

**(1) A new sheet for pages 31, 32, and 33 of claims (translation: pages 39, 39/1, 40 and 41 of claims) 1**